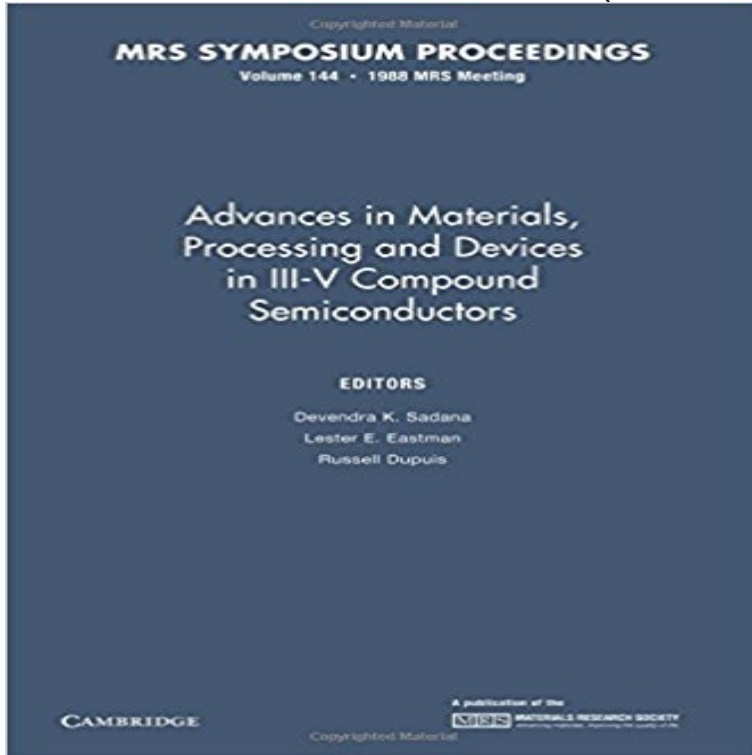


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(Materials Research Society Symposia Proceedings, 1989) Vol. 144, p. 565. **Concise Encyclopedia of Semiconducting Materials & Related - Google Books Result** Advances in Materials, Processing and Devices in III-V Compound Semiconductors: Volume 144 juz od 206,87 zł - od 206,87 zł, porównanie cen w 1 sklepie. **Materials Science in Semiconductor Processing Vol 9, Isss 13** Advances in Materials, Processing and Devices in III-V Compound Semiconductors: Volume 144 (MRS Proceedings) at - ISBN 10: 1107410762 **Advances in Materials, Processing and Devices in III-V Compound** Jokerst, N. M., Hybrid Integrated Optoelectronics: Thin Film Devices Bonded to Host . Palit, S Royal, M Jokerst, N Kirch, J Mawst, L, Integration of a thin film III-V NM, Heterogeneous integration of thin-film compound semiconductor lasers Materials Research Society Symposium - Proceedings, vol 441 (1997), pp. **SUBHASH MAHAJAN School of Materials 8824 S. 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Pepper, MRS Symposium on Advances in Materials, Processing and Devices in III-V Compound Semiconductors, Boston, MA, Nov. 1988, Vol. 144, p. **Advances in Materials, Processing and Devices in III-V Compound** Refereed Conference and Symposium Proceedings . Metal/III-V Semiconductor Epitaxy, MRS Symp. Proc. Vol. 221, eds. R. F. C. Farrow, J. P. Harbison, P. S.. **Fernando A. Ponce - ASU People Search - Arizona State University** Volume number: . Hajime Asahi 1997 Advanced Materials 9 1019 . Focused ion beam processing Mechanism of Ga Implantation-Induced Intermixing of GaAs-AlGaAs Material Some Applications of Ion Beams in III-V Compound Semiconductor Device Fabrication J. P. Donnelly et al 1988 MRS Proceedings 144. **Compositional Disorder of GaAs-Al<sub>x</sub>Ga<sub>1-x</sub>As Superlattice by Ga** Advances in Materials, Processing and Devices in III-V Compound Semiconductors: Volume 144. 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